



## Low-Drop Voltage Regulator

## TLE 4276

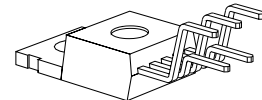
### Features

- 5 V, 8.5 V, 10 V or variable output voltage
- Output voltage tolerance  $\leq \pm 4\%$
- 400 mA current capability
- Low-drop voltage
- Inhibit input
- Very low current consumption
- Short-circuit-proof
- Reverse polarity proof
- Suitable for use in automotive electronics

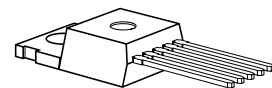
Type	Ordering Code	Package
TLE 4276 V50	Q67000-A9262	P-TO220-5-3
TLE 4276 V85	Q67000-A9263	P-TO220-5-3
TLE 4276 V10	Q67000-A9264	P-TO220-5-3
TLE 4276 V	Q67000-A9265	P-TO220-5-3
TLE 4276 S V50	Q67000-A9267	P-TO220-5-43
TLE 4276 S V85	Q67000-A9269	P-TO220-5-43
TLE 4276 S V10	Q67000-A9271	P-TO220-5-43
TLE 4276 SV	Q67000-A9273	P-TO220-5-43
TLE 4276 G V50	Q67006-A9266	P-TO220-5-122
TLE 4276 G V85	Q67006-A9268	P-TO220-5-122
TLE 4276 G V10	Q67006-A9270	P-TO220-5-122
TLE 4276 GV	Q67006-A9272	P-TO220-5-122
• TLE 4276 D V50	Q67006-A9369	P-TO252-5-1
• TLE 4276 DV	Q67006-A9361	P-TO252-5-1

■ SMD = Surface Mounted Device

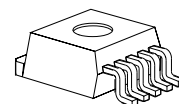
- New type



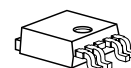
P-TO220-5-3



P-TO-220-5-43



P-TO 220-5-122  
(TO-220 AB/5, Option E3122)



P-TO252-5-1

## Functional Description

The TLE 4276 is a low-drop voltage regulator in a TO package. The IC regulates an input voltage up to 40 V to  $V_{Q,nom} = 5.0\text{ V (V50)}$ ,  $8.5\text{ V (V85)}$ ,  $10\text{ V (V10)}$  and adjustable voltage (V). The maximum output current is 400 mA. The IC can be switched off via the inhibit input, which causes the current consumption to drop below  $10\text{ }\mu\text{A}$ . The IC is short-circuit-proof and includes temperature protection which turns off the device at overtemperature.

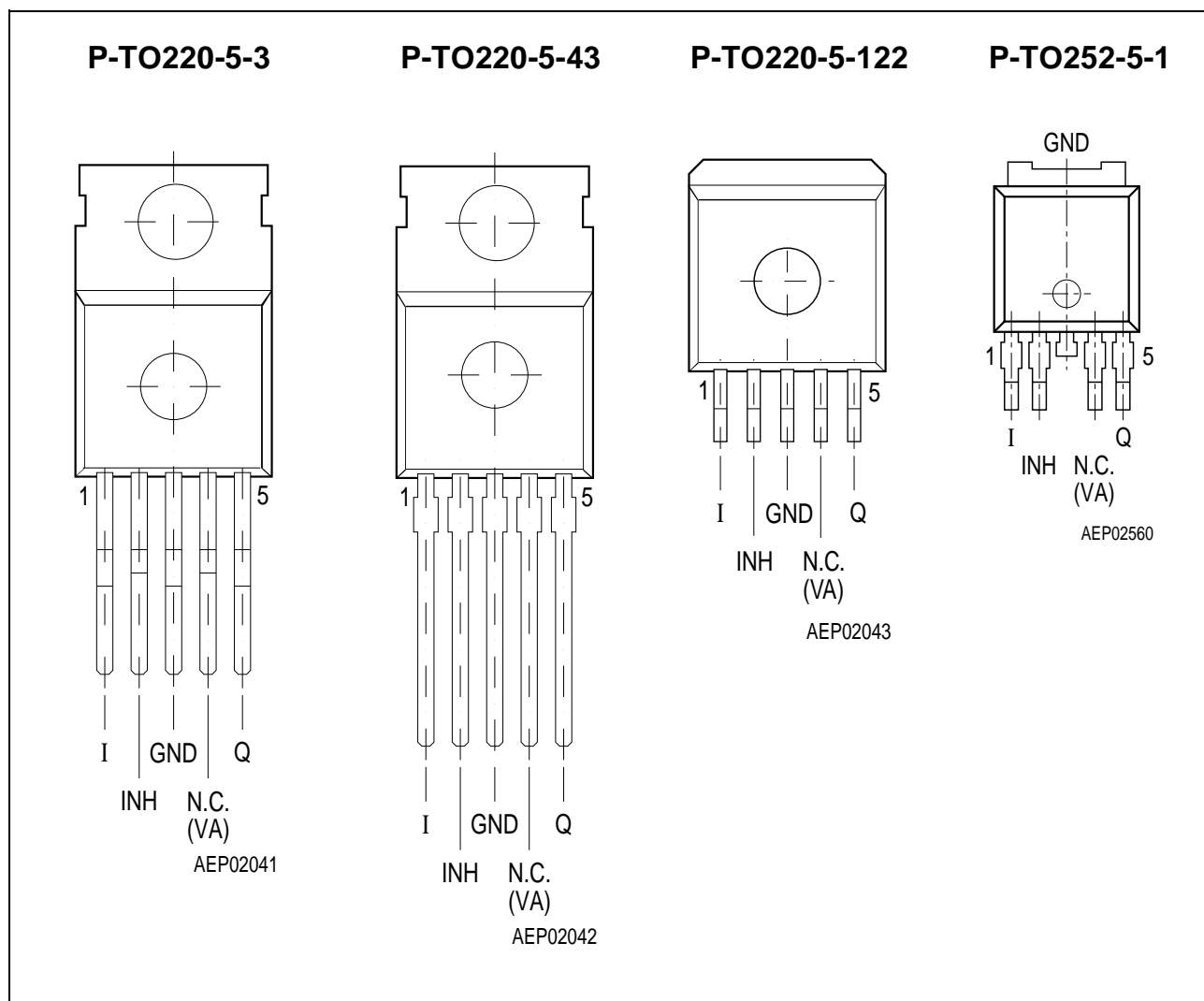
## Dimensioning Information on External Components

The input capacitor  $C_I$  is necessary for compensation of line influences. Using a resistor of approx.  $1\text{ }\Omega$  in series with  $C_I$ , the oscillating of input inductivity and input capacitance can be damped. The output capacitor  $C_Q$  is necessary for the stability of the regulation circuit. Stability is guaranteed at values  $C_Q \geq 22\text{ }\mu\text{F}$  and an ESR of  $\leq 3\text{ }\Omega$  within the operating temperature range.

## Circuit Description

The control amplifier compares a reference voltage to a voltage that is proportional to the output voltage and drives the base of the series transistor via a buffer. Saturation control as a function of the load current prevents any oversaturation of the power element. The IC also incorporates a number of internal circuits for protection against:

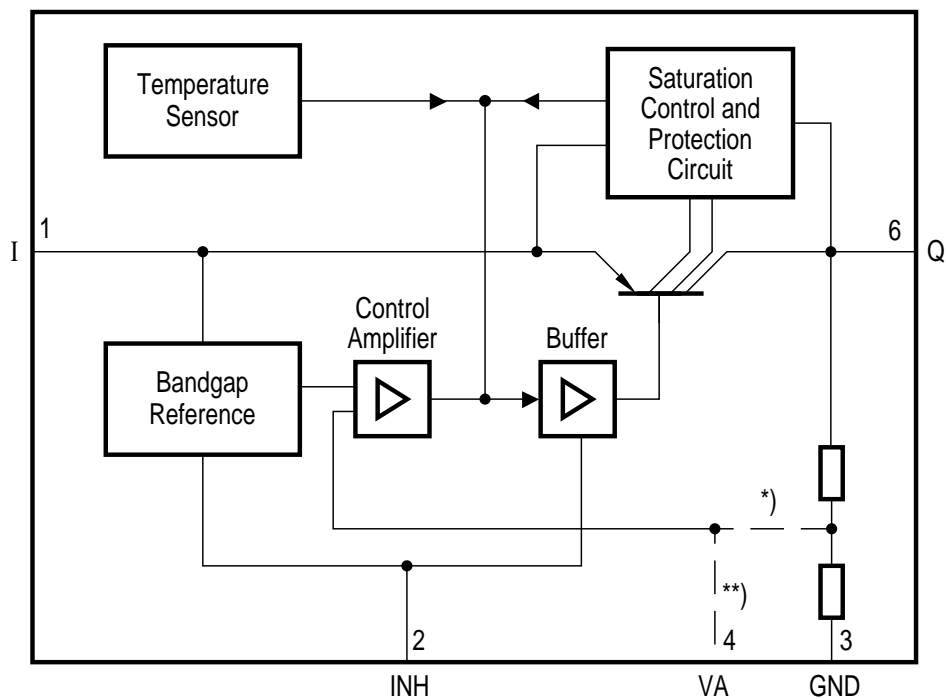
- Overload
- Overtemperature
- Reverse polarity



**Figure 1** Pin Configuration (top view)

## Pin Definitions and Functions

Pin No.	Symbol	Function
1	I	<b>Input</b> ; block to ground directly at the IC with a ceramic capacitor.
2	INH	<b>Inhibit</b> ; low-active input
3	GND	<b>Ground</b>
4	N.C. VA	<b>Not connected</b> for V50, V85, V10 <b>Voltage Adjust Input</b> ; only for adjustable version connect an external voltage divider to determine the output voltage.
5	Q	<b>Output</b> ; block to ground with a capacitor of $C \geq 22 \mu\text{F}$ , $\text{ESR} \geq 3 \Omega$ at 10 kHz.



- \*) For fixed Voltage Regulator only  
 \*\*) For adjustable Voltage Regulator only

AEB02044

**Figure 2 Block Diagram**

## Absolute Maximum Ratings

Parameter	Symbol	Limit Values		Unit	Test Condition
		min.	max.		

## Voltage Regulator

### Input I

Voltage	$V_I$	– 42	45	V	–
Current	$I_I$	–	–	–	Internally limited

### Inhibit INH

Voltage	$V_{INH}$	– 42	45	V	–
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## Voltage Adjust Input VA

Voltage	$V_{VA}$	– 0.3	10	V	–
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## Output Q

Voltage	$V_Q$	– 1.0	40	V	–
Current	$I_Q$	–	–	–	Internally limited

## Ground GND

Current	$I_{GND}$	–	100	mA	–
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## Temperature

Junction temperature	$T_j$	– 40	150	°C	–
Storage temperature	$T_{stg}$	– 50	150	°C	–

*Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.*

## Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Input voltage	$V_I$	$V_Q + 0.5$	40	V	Fixed voltage devices V50, V85, V10
Input voltage	$V_I$	$V_Q + 0.5$	40	V	Variable device V
Input voltage	$V_I$	4.5 V	40	V	Variable device V, $V_Q < 4$ V
Junction temperature	$T_j$	- 40	150	°C	—

## Thermal Resistance

Junction ambient	$R_{thj-a}$	—	65	K/W	TO220
Junction ambient	$R_{thj-a}$	—	80	K/W	TO252, TO263 <sup>1)</sup>
Junction case	$R_{thj-c}$	—	4	K/W	—

<sup>1)</sup> Package mounted on PCB 80 × 80 × 1.5mm<sup>3</sup>; 35μ Cu; 5μ Sn; Footprint only; zero airflow.

## Characteristics

$V_I = 13.5 \text{ V}$ ;  $-40 \text{ }^{\circ}\text{C} < T_j < 150 \text{ }^{\circ}\text{C}$  (unless otherwise specified)

Parameter	Symbol	Limit Values			Unit	Measuring Condition	Measuring Circuit
		min.	typ.	max.			
Output voltage	$V_Q$	4.8	5.0	5.2	V	V50-Version $5 \text{ mA} < I_Q < 400 \text{ mA}$ $6 \text{ V} < V_I < 28 \text{ V}$	1
Output voltage	$V_Q$	4.8	5.0	5.2	V	V50-Version $5 \text{ mA} < I_Q < 200 \text{ mA}$ $6 \text{ V} < V_I < 40 \text{ V}$	1
Output voltage	$V_Q$	8.16	8.50	8.84	V	V85-Version $5 \text{ mA} < I_Q < 400 \text{ mA}$ $9.5 \text{ V} < V_I < 28 \text{ V}$	1
Output voltage	$V_Q$	8.16	8.50	8.84	V	V85-Version $5 \text{ mA} < I_Q < 200 \text{ mA}$ $9.5 \text{ V} < V_I < 40 \text{ V}$	1
Output voltage	$V_Q$	9.6	10.0	10.4	V	V10-Version $5 \text{ mA} < I_Q < 400 \text{ mA}$ $11 \text{ V} < V_I < 28 \text{ V}$	1
Output voltage	$V_Q$	9.6	10.0	10.4	V	V10-Version $5 \text{ mA} < I_Q < 200 \text{ mA}$ $11 \text{ V} < V_I < 40 \text{ V}$	1
Output voltage tolerance	$\Delta V_Q$	- 4	-	4	%	V-Version $R_2 < 50 \text{ k}\Omega$ $V_Q + 1 \text{ V} \leq V_I \leq 40 \text{ V}$ $V_I > 4.5 \text{ V}$ $5 \text{ mA} \leq I_Q \leq 400 \text{ mA}$	1
Output current limitation <sup>1)</sup>	$I_Q$	400	600	1100	mA	-	1
Current consumption; $I_q = I_I - I_Q$	$I_q$	-	-	10	$\mu\text{A}$	$V_{INH} = 0 \text{ V}$ ; $T_j \leq 100 \text{ }^{\circ}\text{C}$	1
Current consumption; $I_q = I_I - I_Q$	$I_q$	-	100	220	$\mu\text{A}$	$I_Q = 1 \text{ mA}$	1
Current consumption; $I_q = I_I - I_Q$	$I_q$	-	5	10	mA	$I_Q = 250 \text{ mA}$	1

### Characteristics (cont'd)

$V_I = 13.5 \text{ V}$ ;  $-40 \text{ }^\circ\text{C} < T_j < 150 \text{ }^\circ\text{C}$  (unless otherwise specified)

Parameter	Symbol	Limit Values			Unit	Measuring Condition	Measuring Circuit
		min.	typ.	max.			
Current consumption; $I_q = I_I - I_Q$	$I_q$	–	15	25	mA	$I_Q = 400 \text{ mA}$	1
Drop voltage <sup>1)</sup>	$V_{DR}$	–	250	500	mV	V50, V85, V10 $I_Q = 250 \text{ mA}$ $V_{DR} = V_I - V_Q$	1
Drop voltage <sup>1)</sup>	$V_{DR}$	–	250	500	mV	variable devices $I_Q = 250 \text{ mA}$ $V_I > 4.5 \text{ V}$ $V_{DR} = V_I - V_Q$	1
Load regulation	$\Delta V_{Q,Lo}$	–	5	35	mV	$I_Q = 5 \text{ mA}$ to 400 mA	1
Line regulation	$\Delta V_{Q,Li}$	–	15	25	mV	$\Delta V_I = 12 \text{ V}$ to 32V $I_Q = 5 \text{ mA}$	1
Power supply ripple rejection	$PSRR$	–	54	–	dB	$f_r = 100 \text{ Hz}$ ; $V_r = 0.5 V_{SS}$	1
Temperature output voltage drift	$dV_Q/dT$	–	0.5	–	–	–	mV/K

### Inhibit

Inhibit on voltage	$V_{INH}$	–	2	3.5	V	$V_Q \geq 4.9 \text{ V}$	1
Inhibit off voltage	$V_{INH}$	0.5	1.7	–	V	$V_Q \leq 0.1 \text{ V}$	1
Input current	$I_{INH}$	5	10	20	$\mu\text{A}$	$V_{INH} = 5 \text{ V}$	1

<sup>1)</sup> Measured when the output voltage  $V_Q$  has dropped 100 mV from the nominal value obtained at  $V_I = 13.5 \text{ V}$ .





### Figure 3 Measuring Circuit

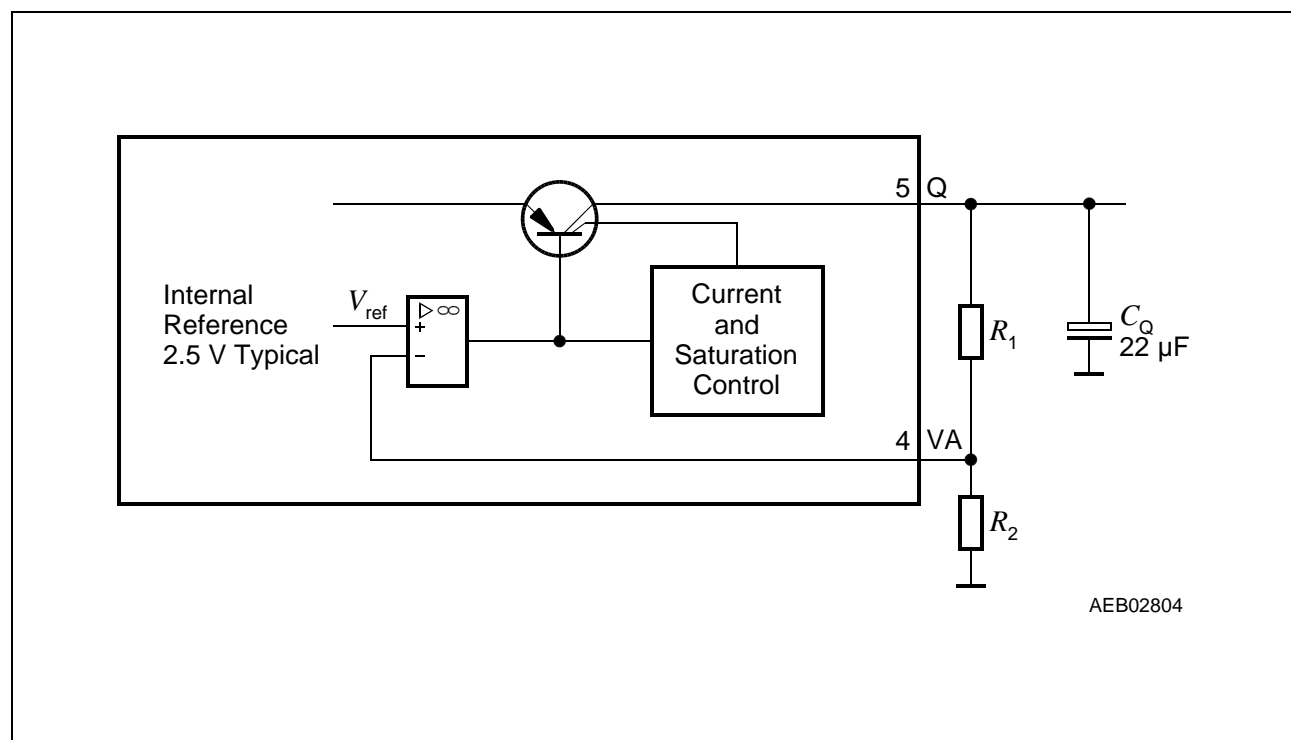


### Figure 4 Application Circuit

## Application Information for Variable Output Regulator TLE 4276 V, SV, DV, GV

The output voltage of the TLE 4276 V can be adjusted between 2.5 V and 20 V by an external output voltage divider, closing the control loop to the voltage adjust pin VA.

The voltage at pin VA is compared to the internal reference of typical 2.5 V in an error amplifier. It controls the output voltage.



**Figure 5 Application Detail External Components at Output for Variable Voltage Regulator**

The output voltage is calculated according to **Equation 1**:

$$V_Q = (R_1 + R_2)/R_2 \times V_{ref}, \text{ neglecting } I_{VA} \quad (1)$$

$V_{ref}$  is typically 2.5 V.

To avoid errors caused by leakage current  $I_{VA}$ , we recommend to choose the resistor value  $R_2$  according to **Equation 2**:

$$R_2 < 50 \text{ k}\Omega \quad (2)$$

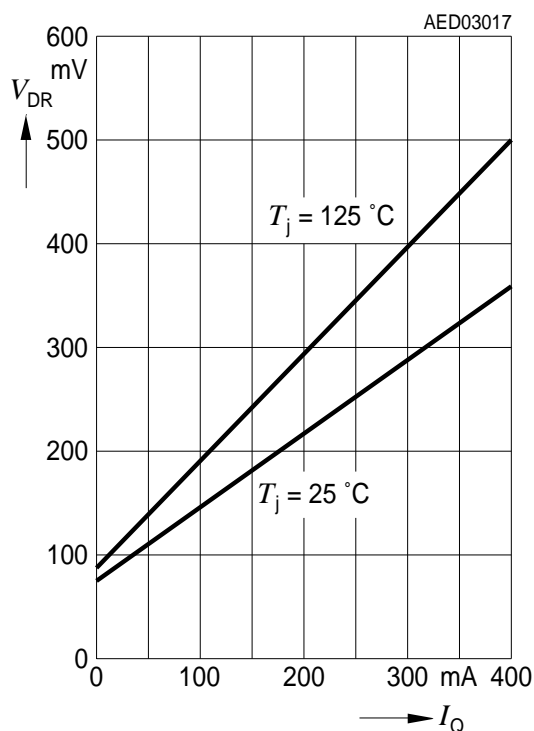
For a 2.5 V output voltage the output pin Q is directly connected to the adjust pin VA.

The accuracy of the resistors  $R_1$  and  $R_2$  add an additional error to the output voltage tolerance.

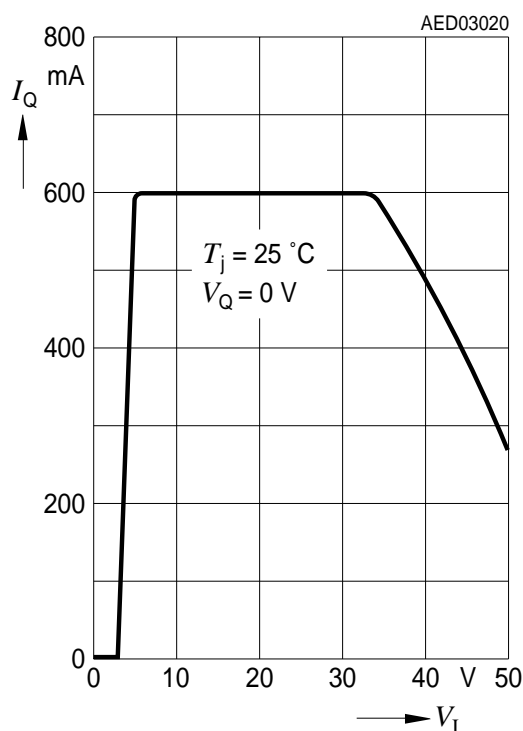
The operation range of the variable TLE 4276 V is  $V_Q + 0.5 \text{ V}$  to 40 V. For internal biasing a minimum input voltage of 4.3 V is required. For output voltages below 4 V the voltage drop is  $4.3 \text{ V} - V_Q$

# Typical Performance Characteristics (V50, V85 and V10):

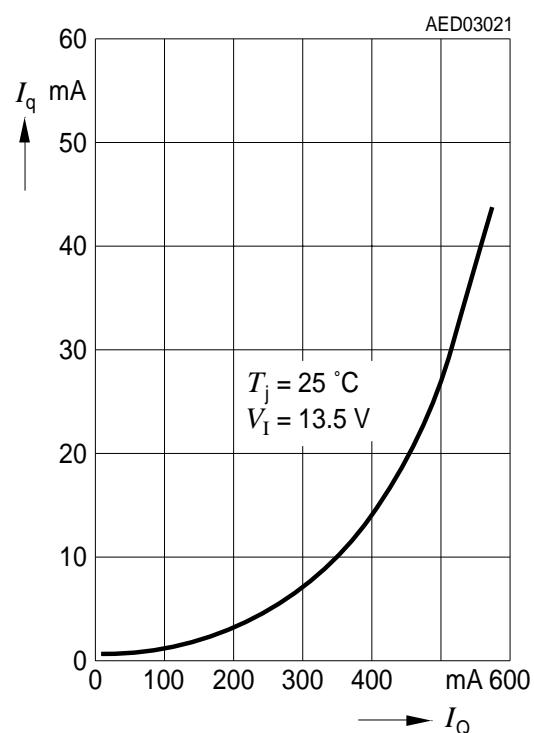
**Voltage  $V_{DR}$  versus Output Current  $I_Q$**



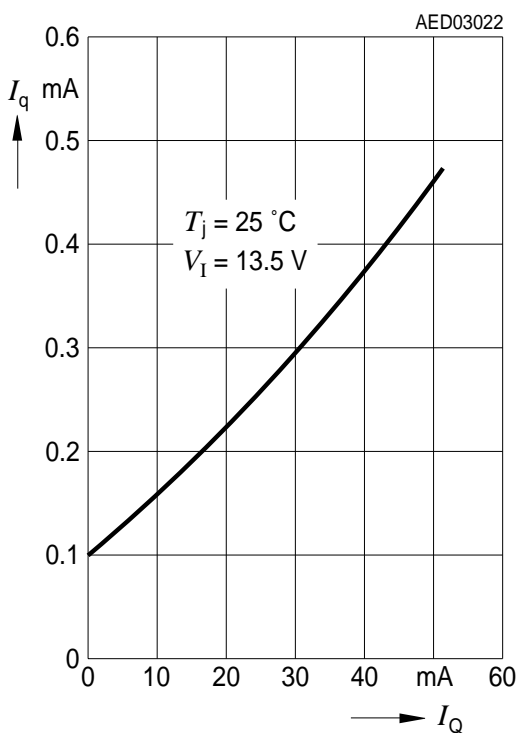
**Max. Output Current  $I_Q$  versus Input Voltage  $V_I$**



**Current Consumption  $I_q$  versus Output Current  $I_Q$  (high load)**

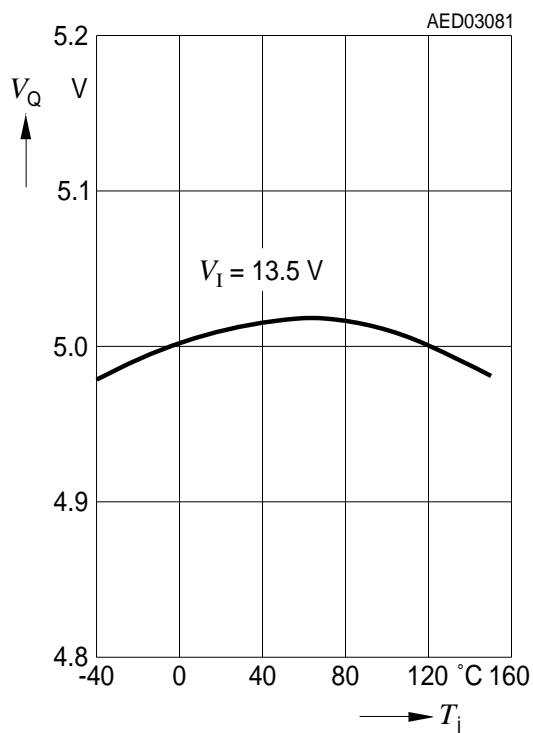


**Current Consumption  $I_q$  versus Output Current  $I_Q$  (low load)**

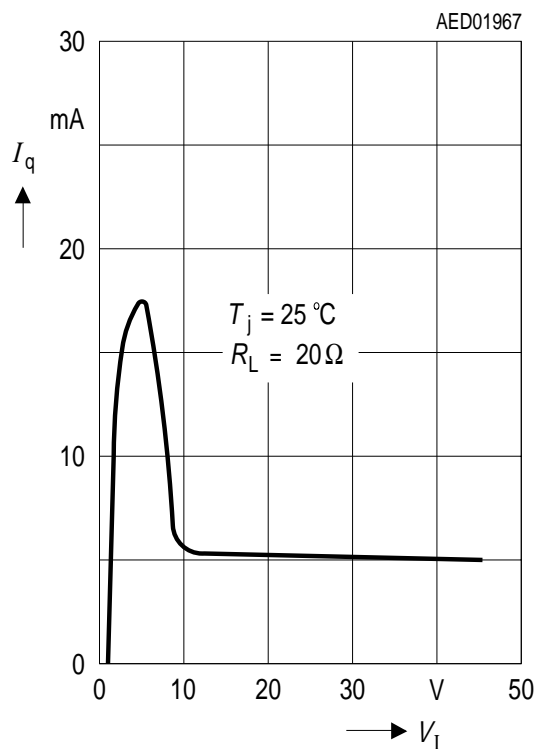


## Typical Performance Characteristics for V50:

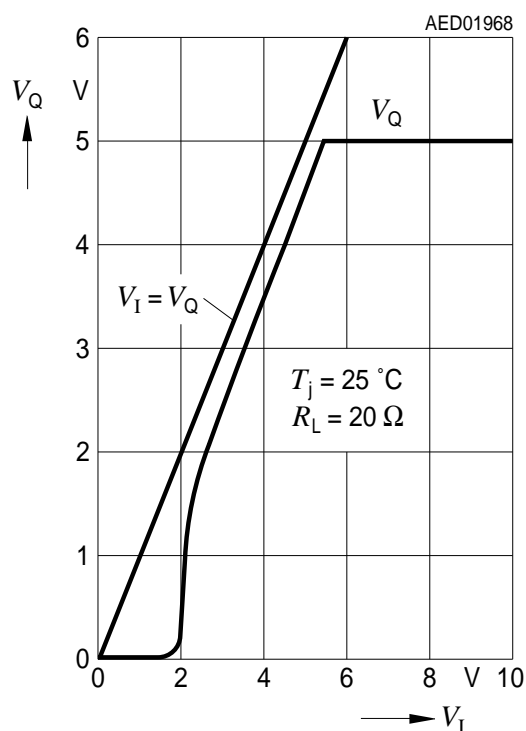
**Output Voltage  $V_Q$  versus Temperature  $T_j$**



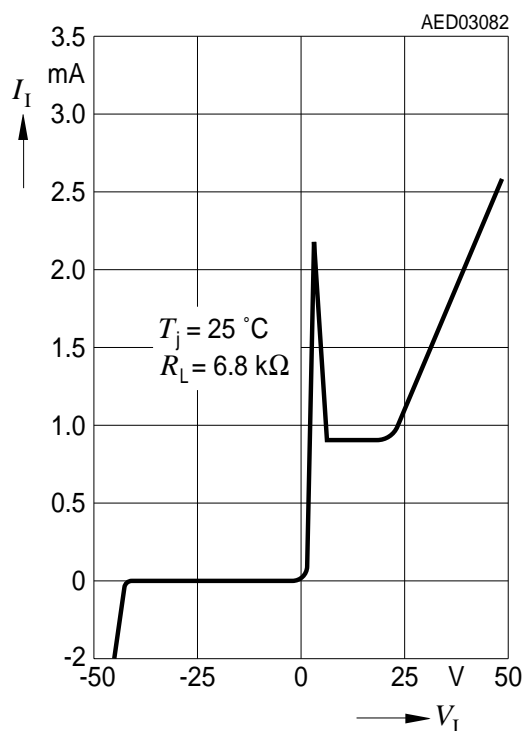
**Current Consumption  $I_q$  versus Input Voltage  $V_I$**



## Low Voltage Behavior

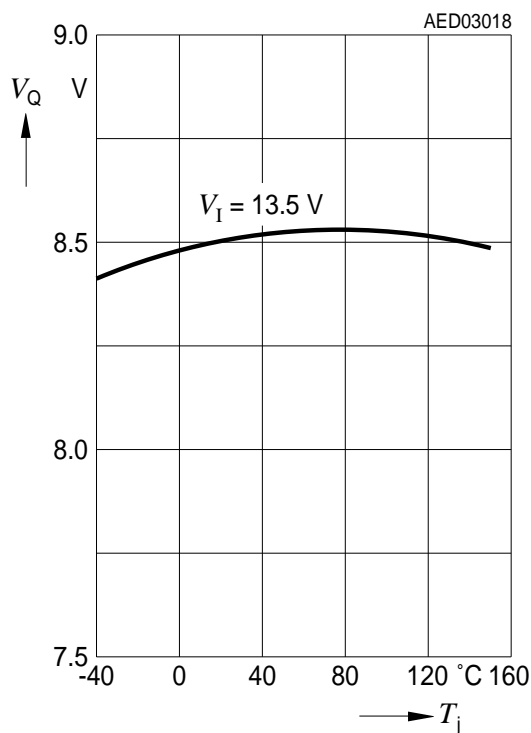


## High Voltage Behavior

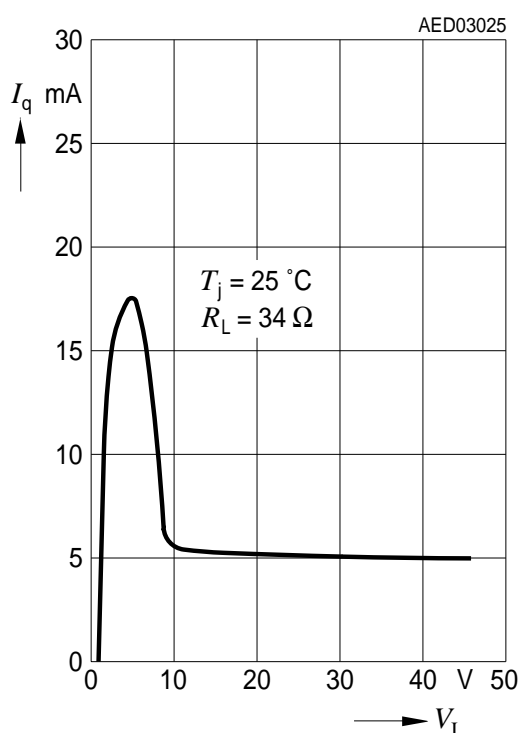


# Typical Performance Characteristics for V85:

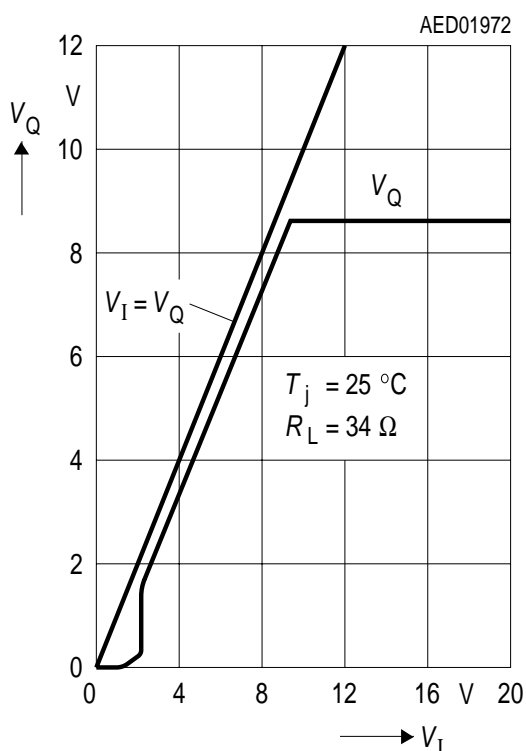
Output Voltage  $V_Q$  versus Temperature  $T_j$



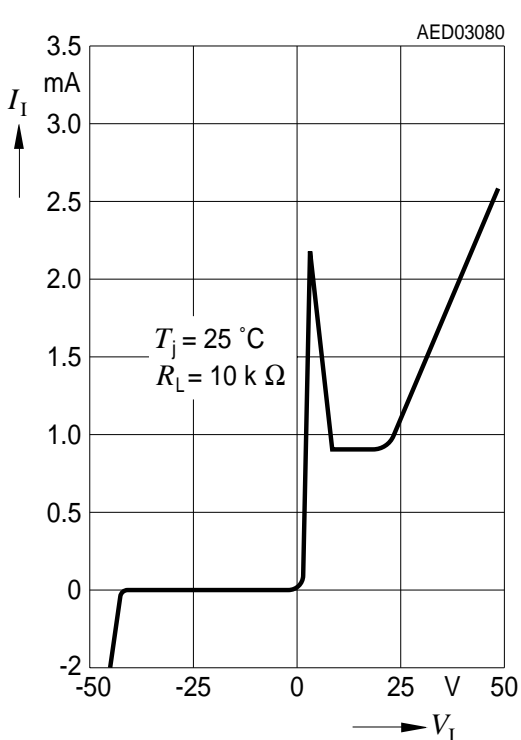
Current Consumption  $I_q$  versus Input Voltage  $V_I$



## Low Voltage Behavior

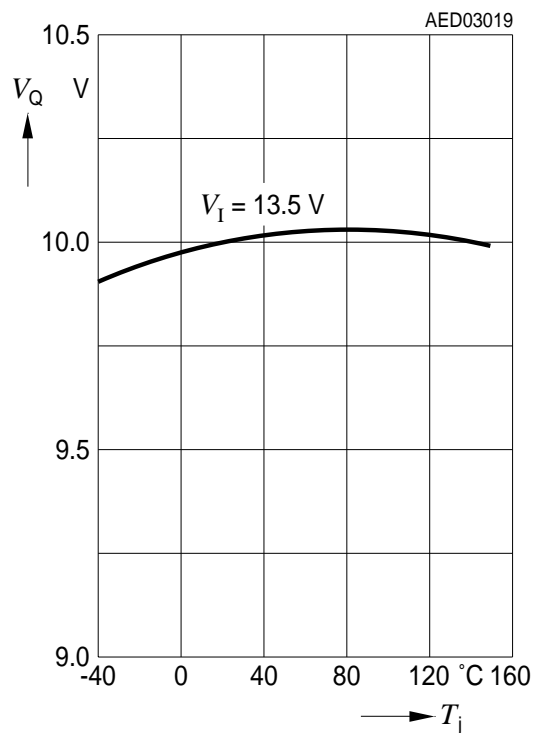


## High Voltage Behavior

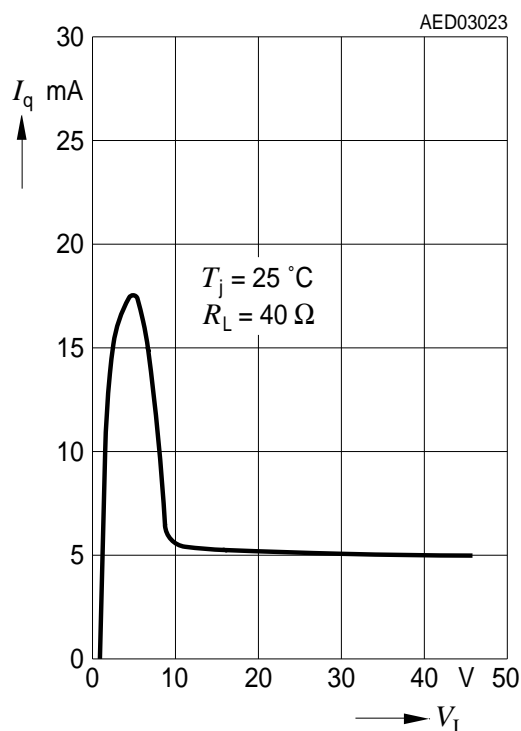


## Typical Performance Characteristics for V10:

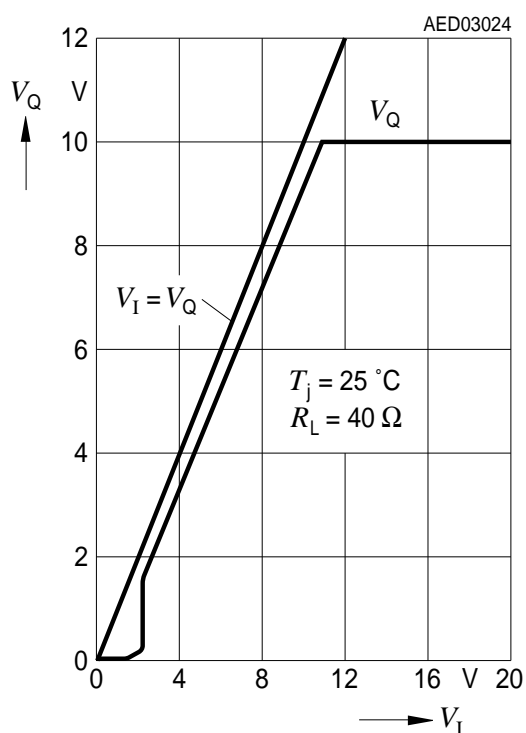
**Output Voltage  $V_Q$  versus Temperature  $T_j$**



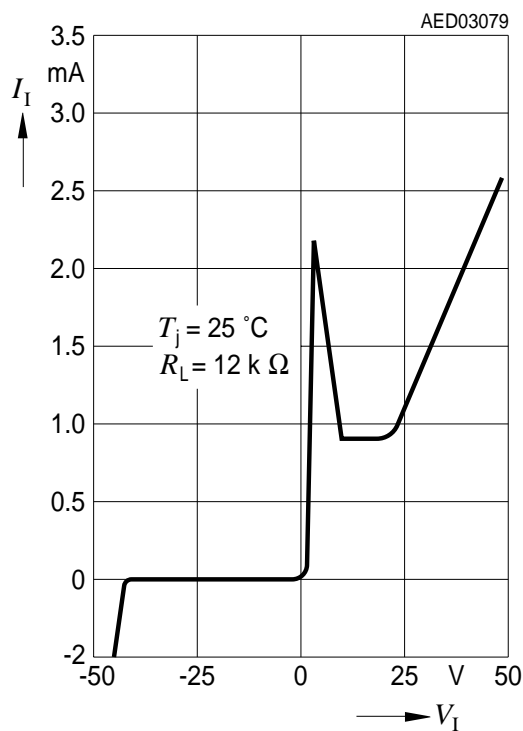
**Current Consumption  $I_q$  versus Input Voltage  $V_I$**



## Low Voltage Behavior



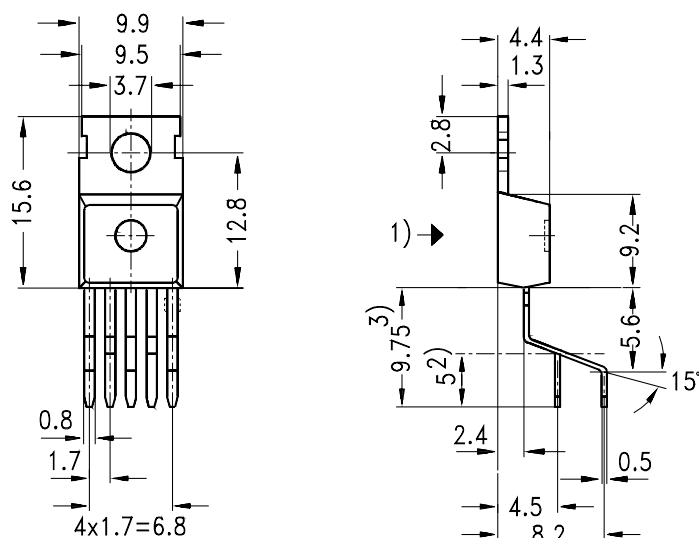
## High Voltage Behavior



## Package Outlines

### P-TO220-5-3

(Plastic Transistor Single Outline)



GPT05165

- 1) shear and punch direction no burrs this surface
- 2) min. length by tinning
- 3) max. 11 mm allowable by tinning

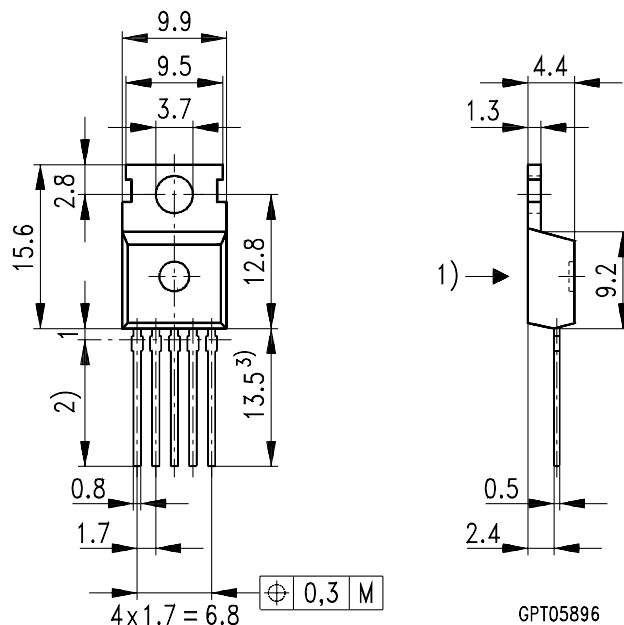
### Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

Dimensions in mm

# P-TO220-5-43

(Plastic Transistor Single Outline)



- 1) Punch direction, burr max. 0.04
- 2) Dip tinning
- 3) Max. 14.5 by dip tinning press burr  
max. 0.05 radii not dimensioned max. 0.2

## Sorts of Packing

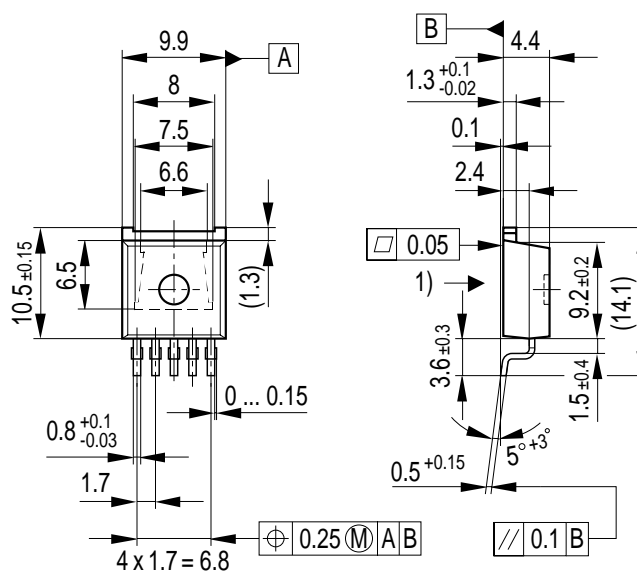
Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

Dimensions in mm



## P-TO220-5-122

(Plastic Transistor Single Outline)



1) Shear and punch direction no burrs this surface

--- Back side, heatsink contour

All metal surfaces tin plated, except area of cut

GPT05259

## Sorts of Packing

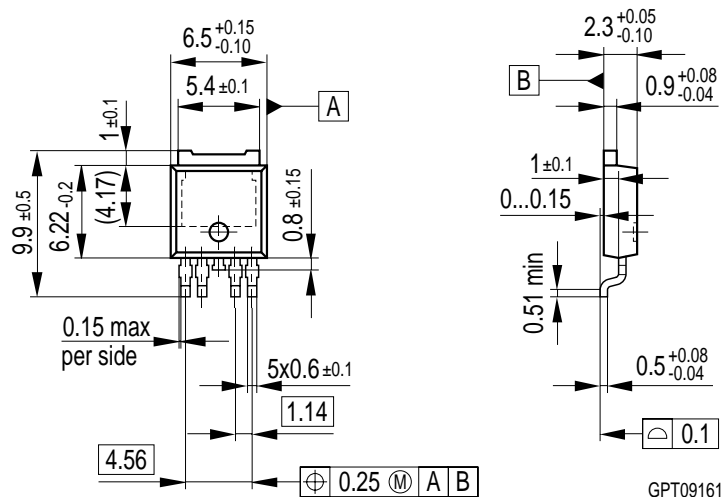
Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

**SMD = Surface Mounted Device**

Dimensions in mm

# P-TO252-5-1

(Plastic Transistor Single Outline)



All metal surfaces tin plated, except area of cut.

## Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

SMD = Surface Mounted Device

Dimensions in mm

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